MOSFET - P-Channel Logic Level PowerTrench®

-40 V, 13.5 mΩ, -50 A

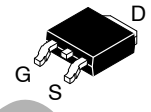
FDD9510L-F085

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Features

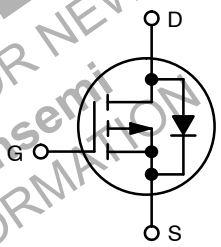
- Typ $R_{DS(on)}$ = 11 mΩ at V_{GS} = −10 V; I_D = −50 A
- Typ $Q_{g(tot)}$ = 28 nC at V_{GS} = −10 V; I_D = −50 A
- UIS Capability
- Qualified to AEC Q101
- These Devices are Pb−Free and are RoHS Compliant



DPAK
TO−252
CASE 369AS

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electrical Power Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12 V Systems



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

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ABSOLUTE MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain to Source Voltage	V_{DSS}	−40	V
Gate to Source Voltage	V_{GS}	±16	V
Drain Current − Continuous (V_{GS} = −10 V) (T_C = 25°C) (Note 1)	I_D	−50	A
Pulsed Drain Current (T_C = 25°C)	I_D	See Figure 4	A
Single Pulse Avalanche Energy (Note 2)	E_{AS}	35.3	mJ
Power Dissipation	P_D	75	W
Derate above 25°C	P_D	0.5	W/°C
Operating and Storage Temperature Range	T_J, T_{STG}	−55 to +175	°C
Thermal Resistance (Junction to Case)	$R_{\theta JC}$	2	°C/W
Maximum Thermal Resistance (Junction to Ambient) (Note 3)	$R_{\theta JA}$	52	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Current is limited by wirebond configuration
2. Starting Tj = 25°C, L = 40 μH, I_{AS} = −42 A, V_{DD} = −40 V during inductor charging and V_{DD} = 0 V during time in avalanche
3. $R_{\theta JA}$ is the sum of the junction−to−case and case−to−ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in^2 pad of 2 oz copper.

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PACKAGE MARKING AND ORDERING INFORMATION

Device	Device Marking	Package	Reel Size	Tape Width	Quantity
FDD9510L−F085	FDD9510L	D−PAK (TO−252)	13″	16 mm	2500 Units

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions		Min	Typ	Max	Unit
OFF CHARACTERISTICS							
BV_{DSS}	Drain to Source Breakdown Voltage	V_{GS} = 0 V, I_D = −250 μA		−40	–	–	V
I_{DSS}	Drain to Source Leakage Current	V_{DS} = −40 V, V_{GS} = 0 V	T_J = 25°C	–	–	−1	μA
			T_J = 175°C (Note 4)	–	–	−1	mA
I_{GSS}	Gate to Source Leakage Current	V_{GS} = ±16 V		–	–	±100	nA
ON CHARACTERISTICS							
$V_{GS(th)}$	Gate to Source Threshold Voltage	V_{GS} = V_{DS}, I_D = 250 μA		−1	−1.9	−3	V
$R_{DS(on)}$	Drain to Source On−Resistance	V_{GS} = −4.5 V, I_D = −50 A, T_J = 25°C		–	16	22	mΩ
		V_{GS} = −10 V, I_D = −50 A	T_J = 25°C	–	11	13.5	mΩ
			T_J = 175°C (Note 4)	–	18	22.7	mΩ
DYNAMIC CHARACTERISTICS							
C_{iss}	Input Capacitance	V_{DS} = −20 V, V_{GS} = 0 V, f = 1 MHz		–	2020	–	pF
C_{oss}	Output Capacitance			–	785	–	pF
C_{rss}	Reverse Transfer Capacitance			–	36	–	pF
R_g	Gate Resistance	V_{GS} = −0.5 V, f = 1 MHz		–	23	–	Ω
$Q_{g(tot)}$	Total Gate Charge	V_{DD} = −20 V, I_D = −50 A	V_{GS} = 0 V to −10 V	–	28	37	nC
$Q_{g(-4.5)}$	Total Gate Charge		V_{GS} = 0 V to −4.5 V	–	13	–	nC
$Q_{g(th)}$	Threshold Gate Charge		V_{GS} = 0 V to −1 V	–	2	–	nC
Q_{gs}	Gate to Source Gate Charge	V_{DD} = −20 V, I_D = −50 A		–	7	–	nC
Q_{gd}	Gate to Drain “Miller” Charge			–	4	–	nC
SWITCHING CHARACTERISTICS							
t_{on}	Turn-On Time	V_{DD} = −20 V, I_D = −50 A, V_{GS} = −10 V, R_{GEN} = 6 Ω		–	–	44	ns
$t_{d(on)}$	Turn-On Delay Time			–	8	–	ns
t_r	Turn-On Rise Time			–	21	–	ns
$t_{d(off)}$	Turn-Off Delay Time			–	113	–	ns
t_f	Turn-Off Fall Time			–	35	–	ns
t_{off}	Turn-Off Time			–	–	220	ns
DRAIN−SOURCE DIODE CHARACTERISTICS							
V_{SD}	Source to Drain Diode Voltage	V_{GS} = 0 V, I_{SD} = −50 A		–	−0.97	−1.25	V
		V_{GS} = 0 V, I_{SD} = −25 A		–	−0.9	−1.2	V
T_{rr}	Reverse Recovery Time	I_F = −50 A, dI_{SD}/dt = 100 A/μs		–	42	63	ns
Q_{rr}	Reverse Recovery Charge			–	31	56	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production

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TYPICAL CHARACTERISTICS

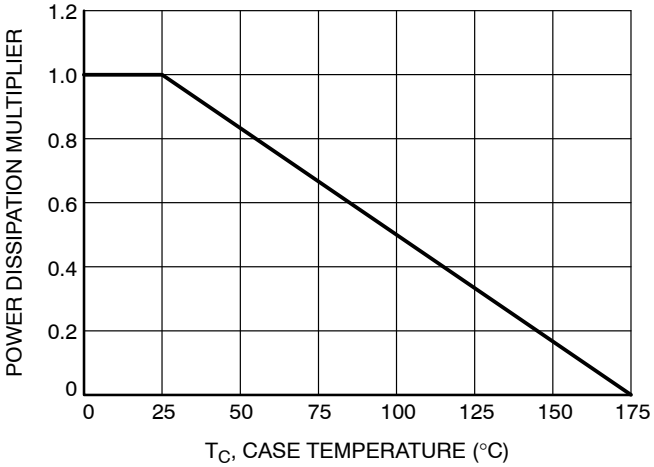


Figure 1. Normalized Power Dissipation vs. Case Temperature

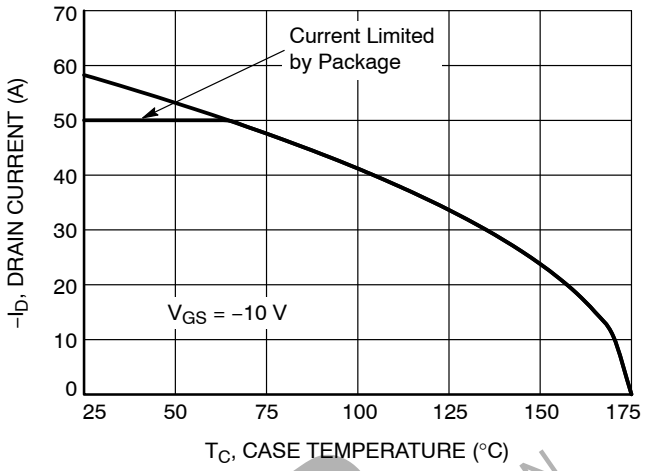


Figure 2. Maximum Continuous Drain Current vs. Case Temperature

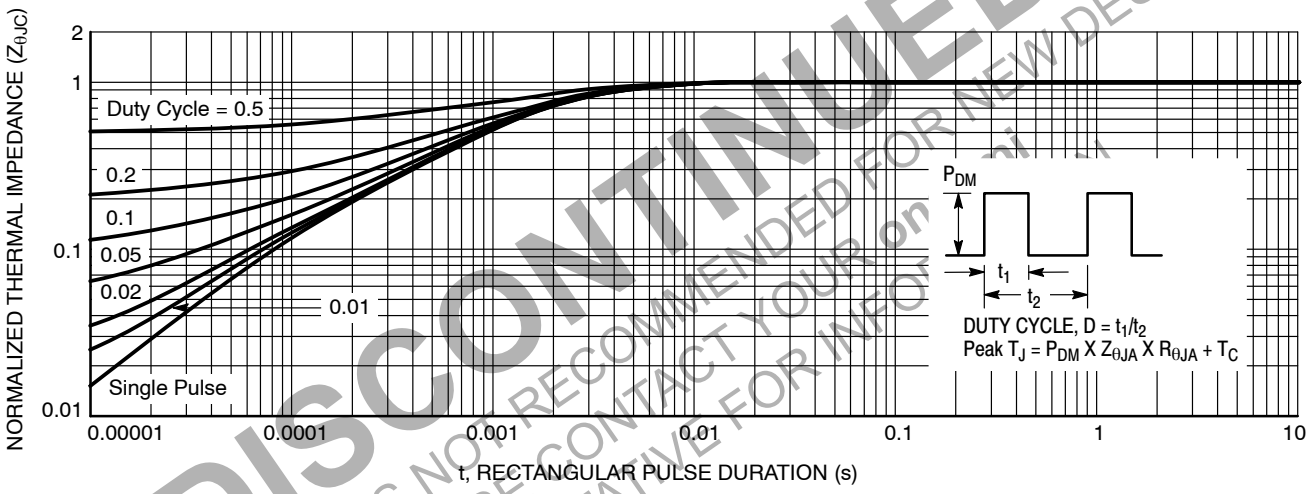


Figure 3. Normalized Maximum Transient Thermal Impedance

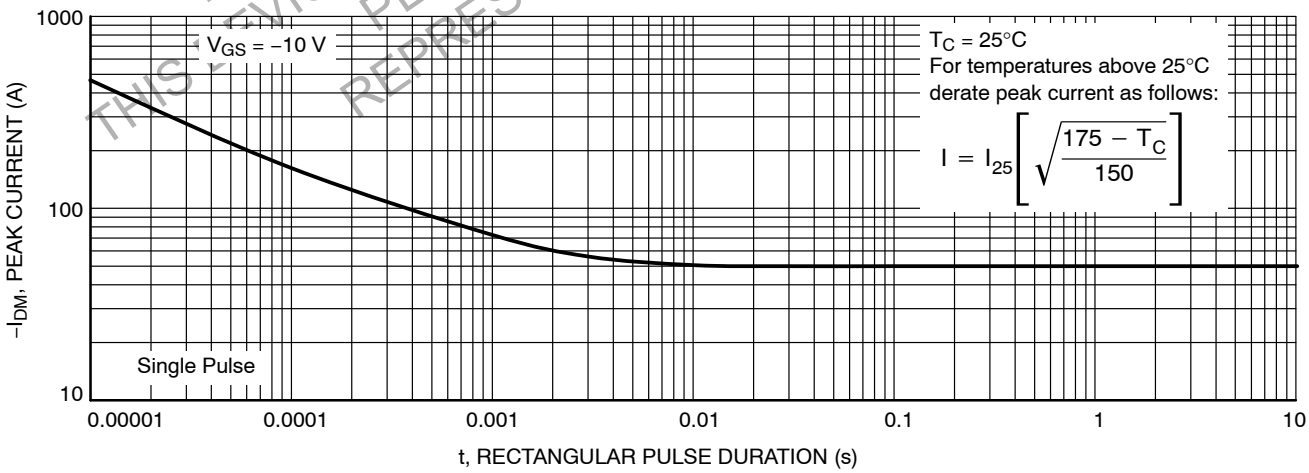


Figure 4. Peak Current Capability

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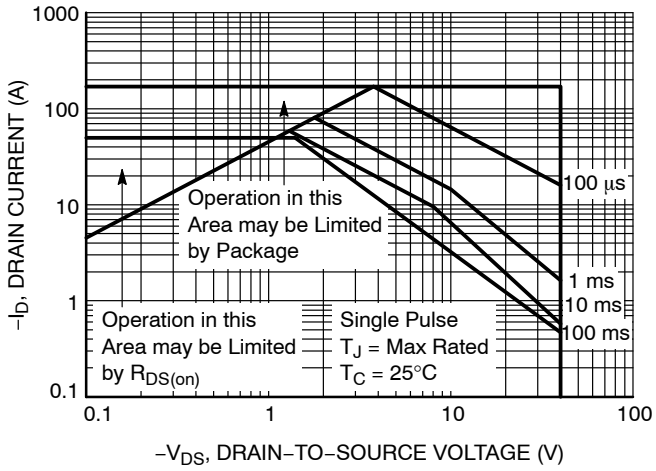


Figure 5. Forward Bias Safe Operating Area

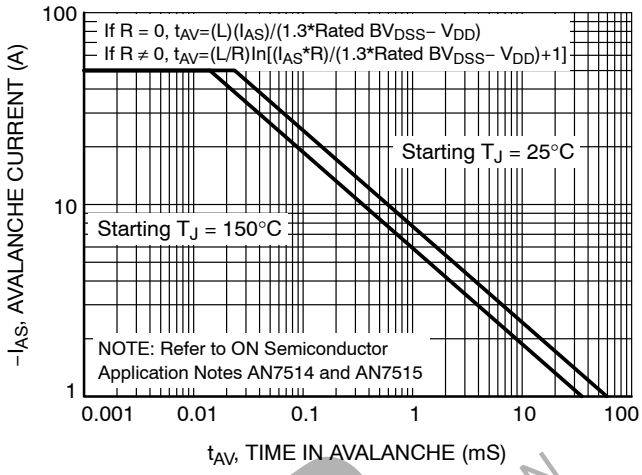


Figure 6. Unclamped Inductive Switching Capability

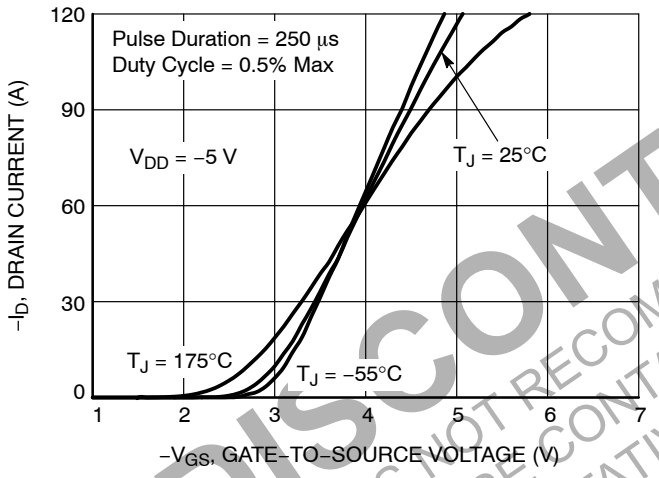


Figure 7. Transfer Characteristics

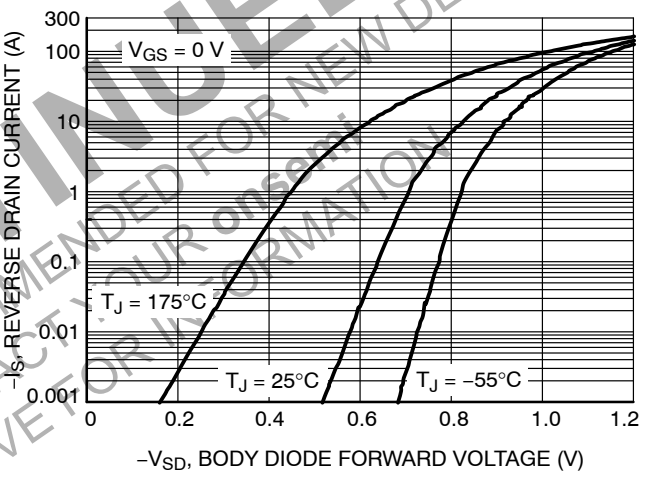


Figure 8. Forward Diode Characteristics

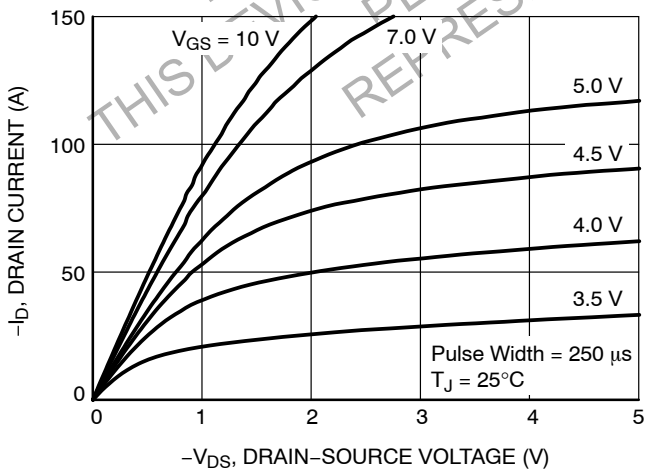


Figure 9. Saturation Characteristics

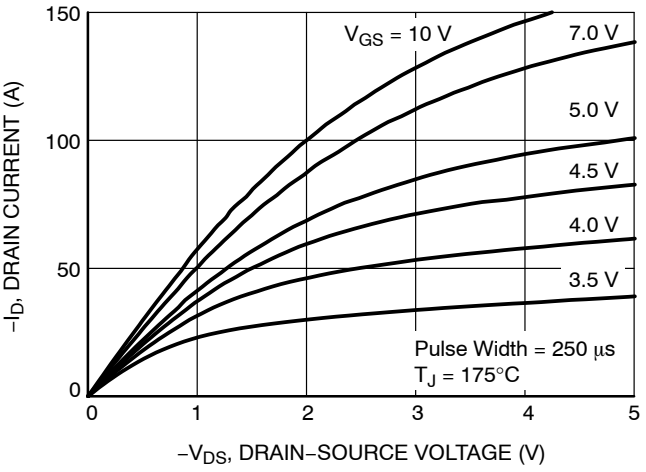


Figure 10. Saturation Characteristics

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TYPICAL CHARACTERISTICS

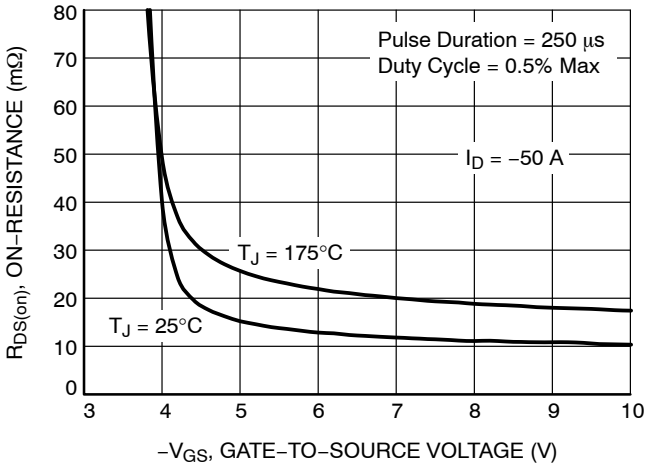


Figure 11. $R_{DS(on)}$ vs. Gate Voltage

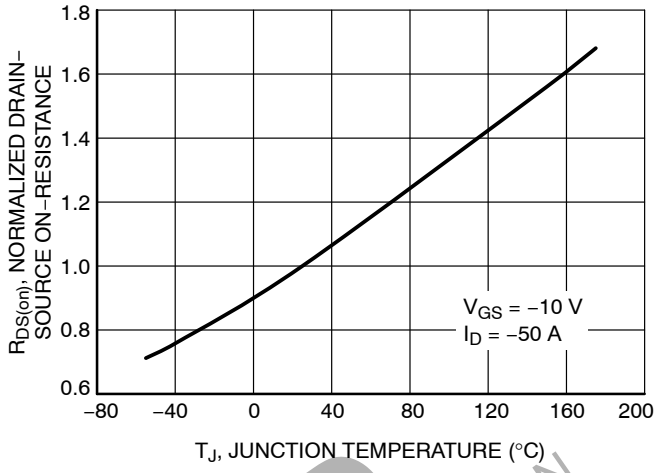


Figure 12. Normalized $R_{DS(on)}$ vs. Junction Temperature

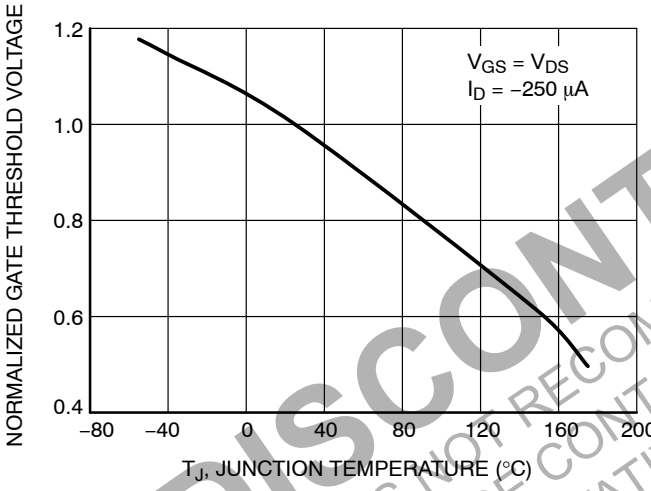


Figure 13. Normalized Gate Threshold Voltage vs. Temperature

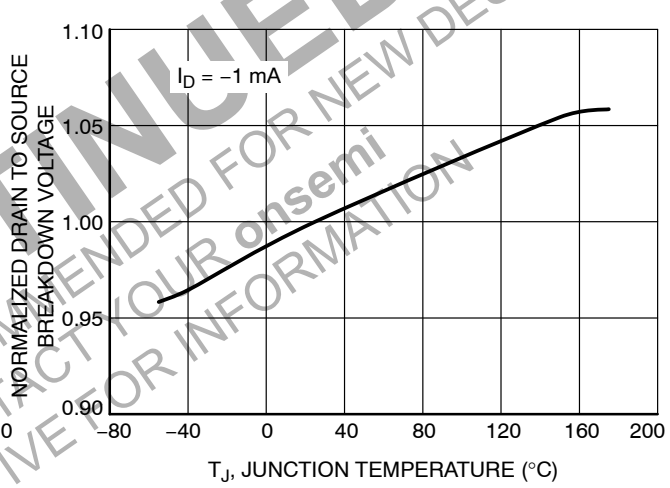


Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

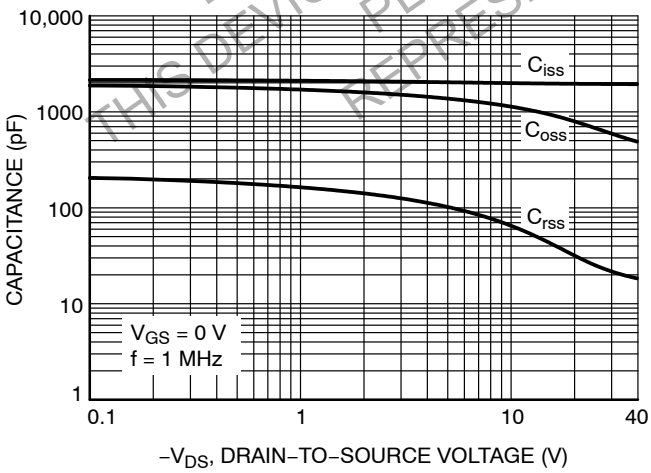


Figure 15. Capacitance vs. Drain to Source Voltage

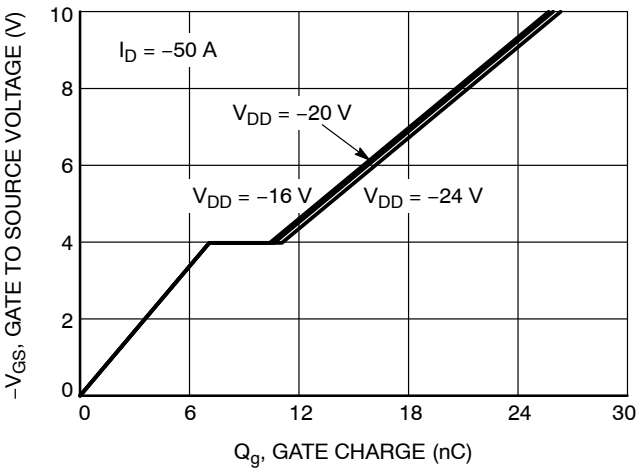
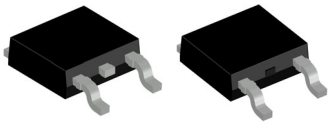


Figure 16. Gate Charge vs. Gate to Source Voltage

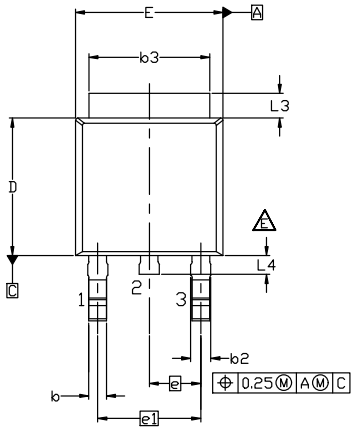
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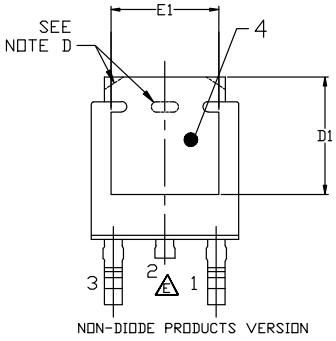


DPAK3 6.10x6.54x2.29, 4.57P
CASE 369AS
ISSUE B

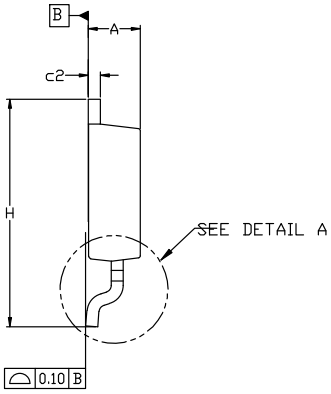
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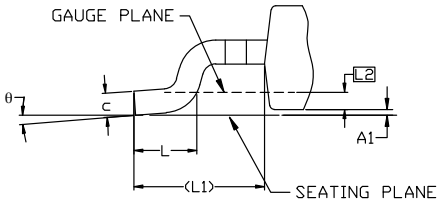
NON-DIODE PRODUCTS VERSION



NON-DIODE PRODUCTS VERSION

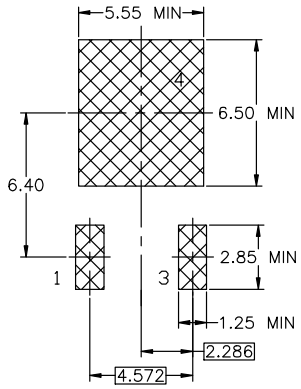


NOTES: UNLESS OTHERWISE SPECIFIED
A) THIS PACKAGE CONFORMS TO JEDEC, TO-252, ISSUE F, VARIATION AA.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-2018.
D) SUPPLIER DEPENDENT MOLD LOCKING HOLES OR CHAMFERED CORNERS OR EDGE PROTRUSION.
E) FOR DIODE PRODUCTS, L4 IS 0.25 MM MAX PLASTIC BODY STUB WITHOUT CENTER LEAD.
F) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
G) LAND PATTERN RECOMMENDATION IS BASED ON IPC7351A STD TO228P991X239-3N.



DETAIL A
(ROTATED -90°)
SCALE: 12X

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	2.18	2.29	2.39
A1	0.00	–	0.127
b	0.64	0.77	0.89
b2	0.76	0.95	1.14
b3	5.21	5.34	5.46
c	0.45	0.53	0.61
c2	0.45	0.52	0.58
D	5.97	6.10	6.22
D1	5.21	---	---
E	6.35	6.54	6.73
E1	4.32	---	---
e	2.286 BSC		
e1	4.572 BSC		
H	9.40	9.91	10.41
L	1.40	1.59	1.78
L1	2.90 REF		
L2	0.51 BSC		
L3	0.89	1.08	1.27
L4	---	---	1.02
θ	0°	---	10°



LAND PATTERN RECOMMENDATION

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.

XXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
ZZ = Assembly Lot Code

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DESCRIPTION:	**DPAK3 6.10x6.54x2.29, 4.57P**	**PAGE 1 OF 1**

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Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

www.entegreci.com

Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

www.entegreci.com | **destek@entegreci.com** | **0850 305 90 34**

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Bu sayfa Entegreci tarafından eklenmiştir. Belgenin önceki sayfaları asıl yayıncısına aittir ve içeriği değiştirilmemiştir; en güncel sürüm için belgenin yayıncısına başvurun.